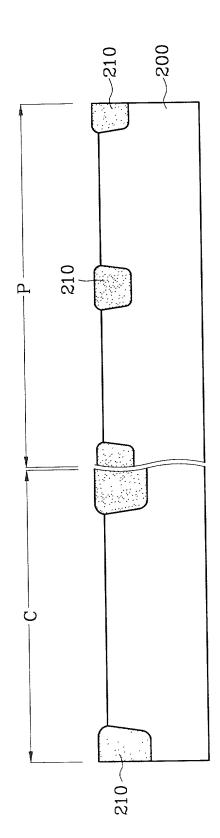
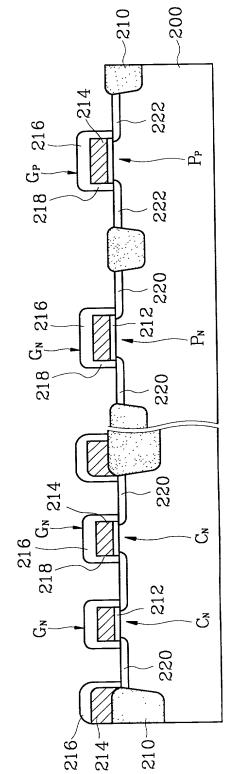


AREA Attorney Docket No. 9898-201/Application No.



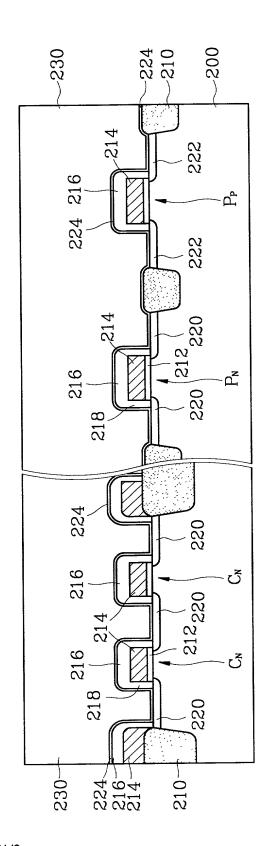


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 $\label{eq:KEA} Attorney \ Docket \ Mo. \ 9898-201/Application \ Mo.$

WELHOD OF FORMING SEMICONDUCTOR DEVICE HAVING CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT AND OF FORMING SEMICONDUCTOR DEVICED AND CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT

FIG. 4

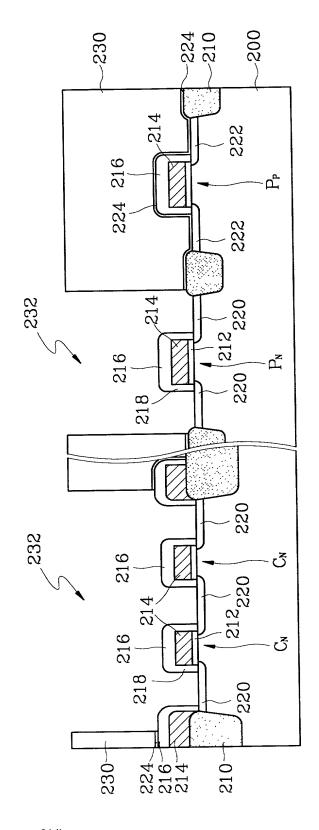


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WELHOD OF FORMING SEMICONDUCTOR DEVICE HAVING CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT

AREA

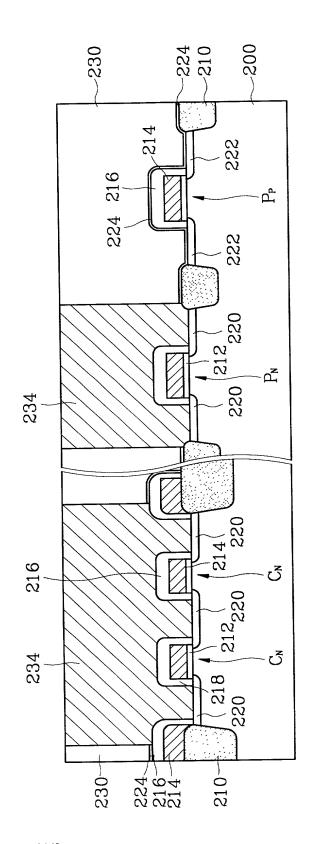
Kang-Yoon LEE



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 $\begin{tabular}{ll} AREA \\ Attorney Docket No. 9898-201/Application No. \\ \end{tabular}$

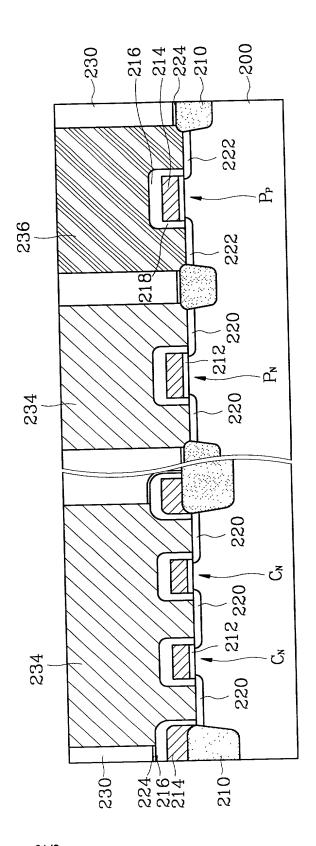
WELHOD OF FORMING SEMICONDUCTOR DEVICE HAVING CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT



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Attorney Docket No. 9898-201/Application No.

WELHOD OF FORMING SEMICONDUCTOR DEVICE HAVING CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT KANGE CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT



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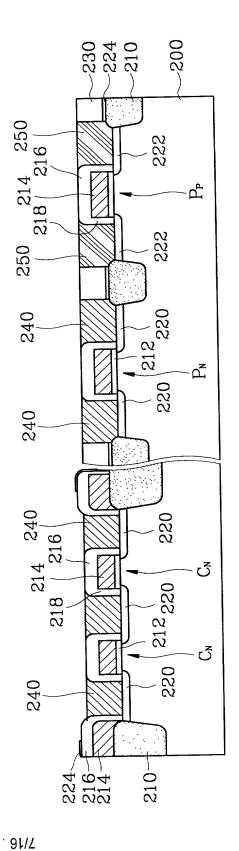
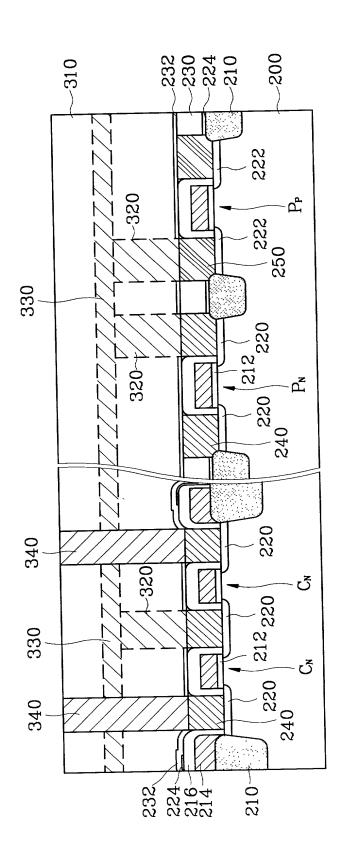


FIG. 9

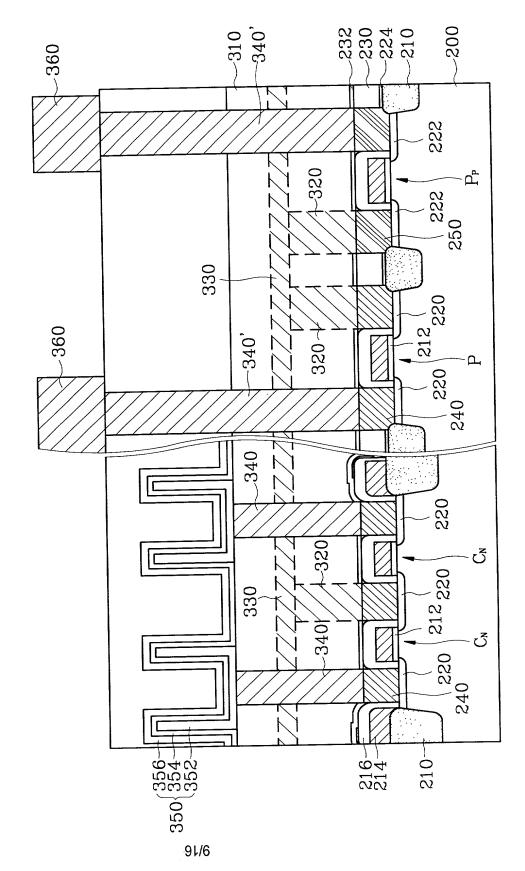


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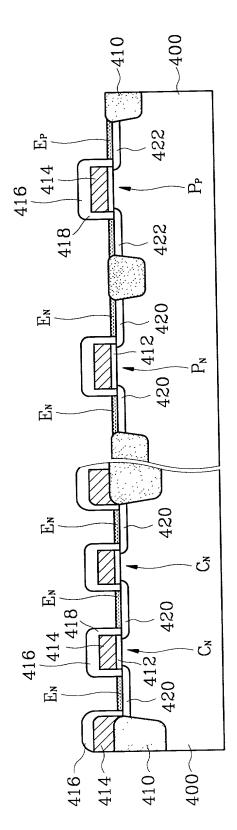
 $\mbox{AREA} \label{eq:AREA} \mbox{Attorney Docket No. 9898-201/Application Mo.}$

WELHOD OF FORMING SEMICONDUCTOR DEVICE HAVING CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT Kang-Yoon Lee

FIG. 10

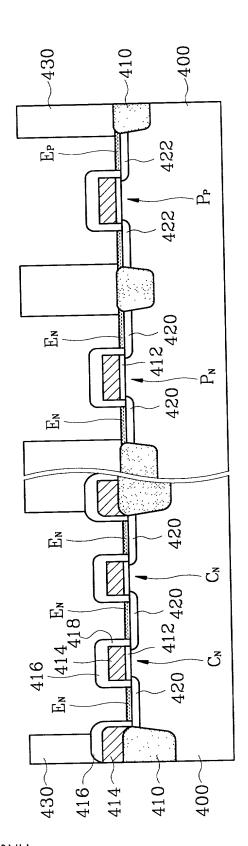


WELHOD OF FORMING SEMICONDUCTOR DEVICE HAVING CONTACT PAD ON SOURCE/DRAIN REGION IN PERIPHERAL CIRCUIT Kang-Yoon LEE



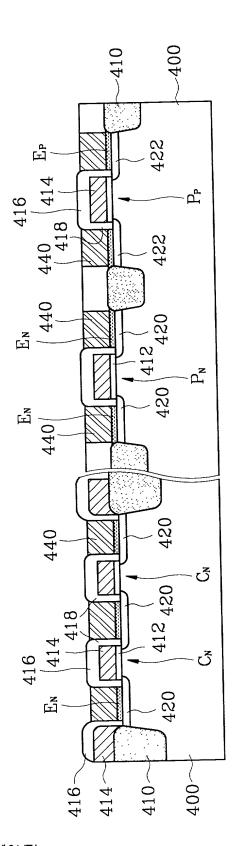
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FIG 12



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FIG. 13



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FIG. 14A

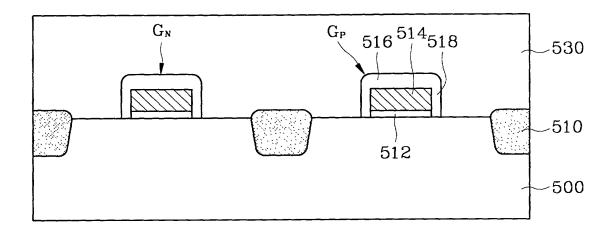
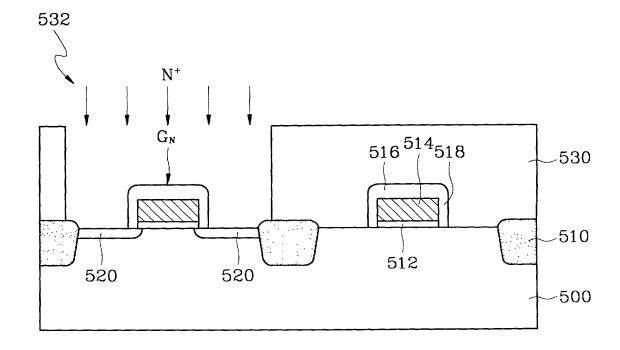


FIG. 14B



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FIG. 14C

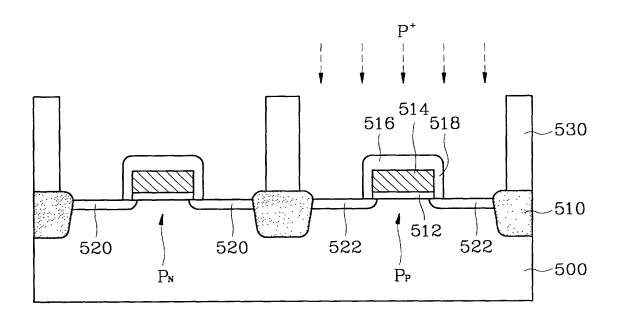
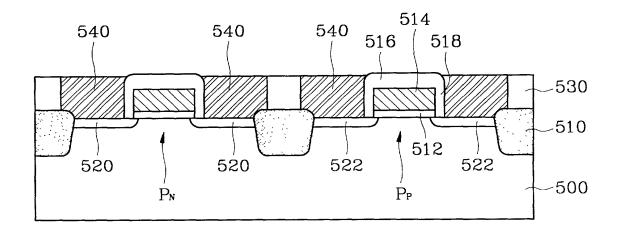


FIG. 14D



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FIG. 15A

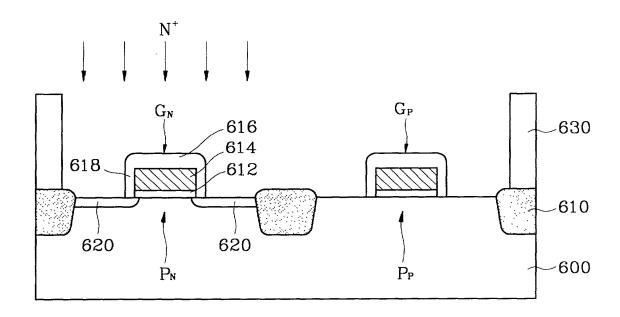
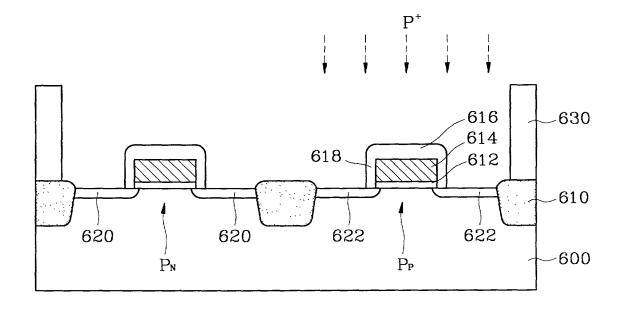


FIG. 15B



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FIG. 15C

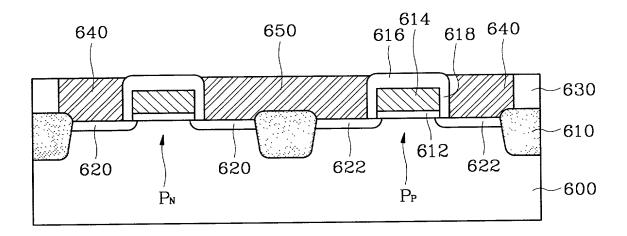


FIG. 16 (PRIOR ART)

